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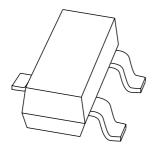
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

## **DISCRETE SEMICONDUCTORS**

# DATA SHEET



# PMBTA13; PMBTA14 NPN Darlington transistors

Product data sheet Supersedes data of 1999 Apr 29 2004 Jan 22



## **NPN Darlington transistors**

## PMBTA13; PMBTA14

#### **FEATURES**

- High current (max. 500 mA)
- Low voltage (max. 30 V)
- High DC current gain (min. 10000).

#### **APPLICATIONS**

• High input impedance preamplifiers.

#### **DESCRIPTION**

NPN Darlington transistor in a SOT23 plastic package. PNP complement: PMBTA64.

#### **MARKING**

TYPE NUMBER	MARKING CODE <sup>(1)</sup>
PMBTA13	*1M
PMBTA14	*1N

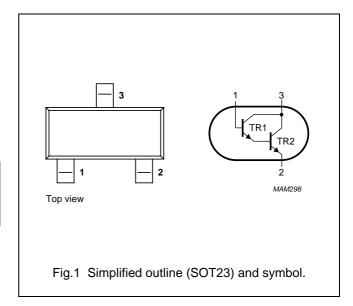
#### Note

\* = p : Made in Hong Kong.
 \* = t : Made in Malaysia.

\* = W : Made in China.

#### **PINNING**

PIN	DESCRIPTION
1	base
2	emitter
3	collector



#### **ORDERING INFORMATION**

TYPE PACKAGE					
NUMBER	NAME	NAME DESCRIPTION			
PMBTA13	_	plastic surface mounted package; 3 leads	SOT23		
PMBTA14					

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# NPN Darlington transistors

PMBTA13; PMBTA14

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	_	30	V
V <sub>CES</sub>	collector-emitter voltage	V <sub>BE</sub> = 0	_	30	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	10	V
Ic	collector current (DC)		_	500	mA
I <sub>CM</sub>	peak collector current		_	800	mA
I <sub>B</sub>	base current (DC)		_	200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	note 1	500	K/W

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### **CHARACTERISTICS**

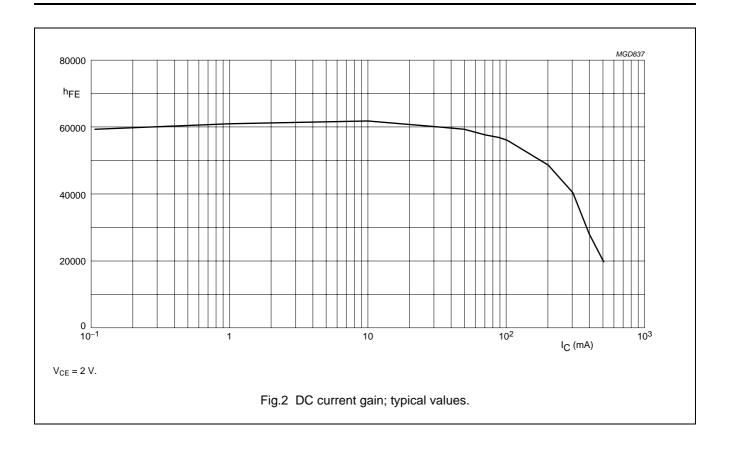
 $T_i = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = 30 V	_	100	nA
I <sub>EBO</sub>	emitter cut-off current	I <sub>C</sub> = 0; V <sub>EB</sub> = 10 V	_	100	nA
h <sub>FE</sub>	DC current gain	$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}; \text{ (see Fig.2)}$			
	PMBTA13		5000	_	
	PMBTA14		10000	_	
	DC current gain	$I_C = 100 \text{ mA}; V_{CE} = 5 \text{ V}; \text{ (see Fig.2)}$			
	PMBTA13		10000	_	
	PMBTA14		20000	_	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 100 \text{ mA}; I_B = 0.1 \text{ mA}$	_	1.5	V
$V_{BEon}$	base-emitter on-state voltage	$I_C = 100 \text{ mA}; V_{CE} = 5 \text{ V}$	_	1.4	V
f <sub>T</sub>	transition frequency	$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}; f = 100 \text{ MHz}$	125	_	MHz

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# NPN Darlington transistors

# PMBTA13; PMBTA14



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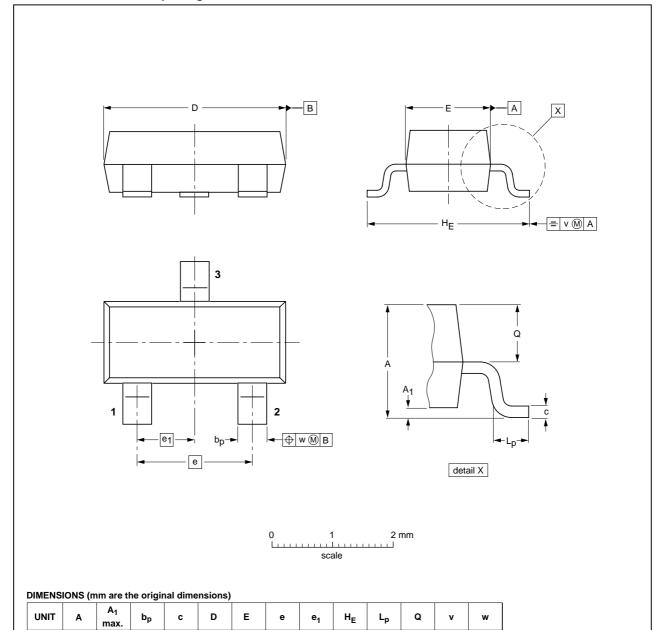
# NPN Darlington transistors

## PMBTA13; PMBTA14

#### **PACKAGE OUTLINE**

#### Plastic surface-mounted package; 3 leads

SOT23



OUTLINE		REFER	REFERENCES EUROPEAN ISSUE		ICCUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT23		TO-236AB			F-7-6	<del>-04-11-04</del>

0.45

0.55

0.1

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0.38

0.9

### NPN Darlington transistors

PMBTA13; PMBTA14

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### **Notes**

- 1. Please consult the most recently issued document before initiating or completing a design.
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### **NXP Semiconductors**

#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

For additional information please visit: http://www.nxp.com
For sales offices addresses send e-mail to: salesaddresses@nxp.com

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Printed in The Netherlands R75/05/pp7 Date of release: 2004 Jan 22 Document order number: 9397 750 12507



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